

Amplifier Transistors PNP Silicon

2N5401^{*}

*ON Semiconductor Preferred Device

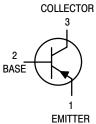
MAXIMUM RATINGS

Rating	Symbol	2N5400	2N5401	Unit
Collector–Emitter Voltage	VCEO	120	150	Vdc
Collector–Base Voltage	Vсво	130	160	Vdc
Emitter–Base Voltage	VEBO	5.0		Vdc
Collector Current — Continuous	IC	600		mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	625 5.0		mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12		Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150		°C



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS		<u>.</u>		•	•
Collector–Emitter Breakdown Voltage(1) (I _C = 1.0 mAdc, I _B = 0)	2N5400 2N5401	V(BR)CEO	150	_	Vdc
Collector–Base Breakdown Voltage (I _C = 100 μ Adc, I _E = 0)	2N5400 2N5401	V(BR)CBO	160	_	Vdc
Emitter–Base Breakdown Voltage $(I_E = 10 \mu Adc, I_C = 0)$		V(BR)EBO	5.0	_	Vdc
Collector Cutoff Current (V _{CB} = 120 Vdc, I _E = 0) (V _{CB} = 120 Vdc, I _E = 0, T _A = 100°C)	2N5401 2N5401	ICBO	_	50 50	
Emitter Cutoff Current (VEB = 3.0 Vdc, I _C = 0)		I _{EBO}	_	50	nAdc

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle = 2.0%.

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

2N5401

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

宣刊"2N54017D" 共应商 Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS(1)				l.
DC Current Gain (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc) (I _C = 10 mAdc, V _{CE} = 5.0 Vdc) (I _C = 50 mAdc, V _{CE} = 5.0 Vdc)	hFE	50 60 50	 240 	_
Collector–Emitter Saturation Voltage (I _C = 10 mAdc, I _B = 1.0 mAdc) (I _C = 50 mAdc, I _B = 5.0 mAdc)	VCE(sat)	_ _	0.2 0.5	Vdc
Base–Emitter Saturation Voltage (I _C = 10 mAdc, I _B = 1.0 mAdc) (I _C = 50 mAdc, I _B = 5.0 mAdc)	VBE(sat)	_	1.0 1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS	<u> </u>		•	•
Current–Gain — Bandwidth Product (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 100 MHz)	fT	100	300	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	6.0	pF
Small–Signal Current Gain (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	40	200	_
Noise Figure (I _C = 250 μ Adc, V _{CE} = 5.0 Vdc, R _S = 1.0 k Ω , f = 1.0 kHz)	NF	_	8.0	dB

^{1.} Pulse Test: Pulse Width = $300 \mu s$, Duty Cycle = 2.0%.

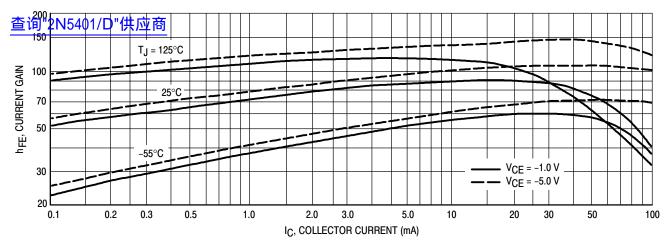


Figure 1. DC Current Gain

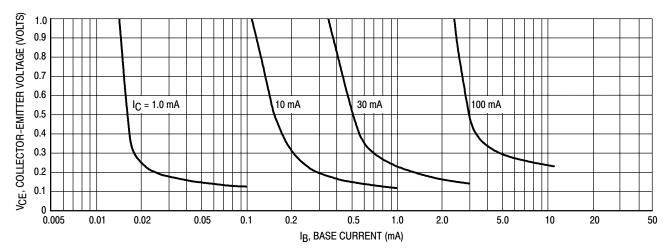


Figure 2. Collector Saturation Region

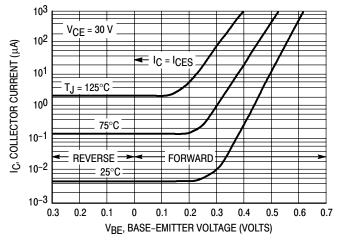


Figure 3. Collector Cut-Off Region

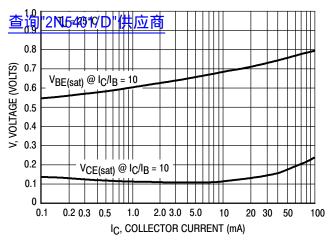


Figure 4. "On" Voltages

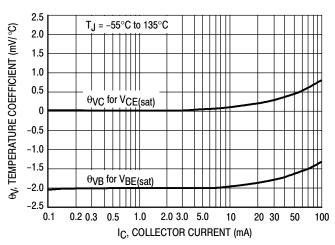
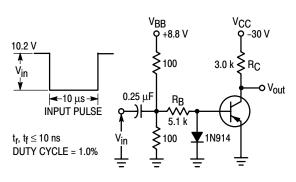


Figure 5. Temperature Coefficients



Values Shown are for I $_{\hbox{\scriptsize C}}$ @ 10 mA

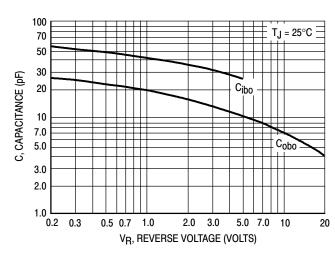


Figure 7. Capacitances

Figure 6. Switching Time Test Circuit

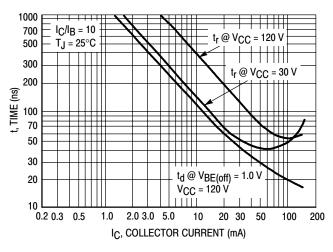


Figure 8. Turn-On Time

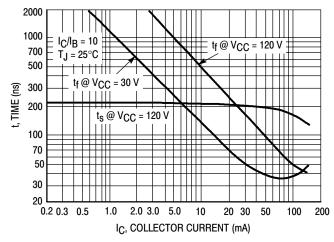
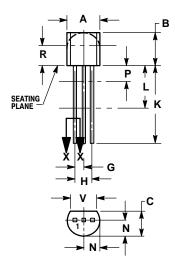


Figure 9. Turn-Off Time

查询"2N5401/D"供应商

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

2N5401



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